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WHAT IS CLAIMED IS:

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- A method for analyzing defects on a substrate, the method including the steps of:
 inspecting the substrate to detect the defects,
 identifying the defects by location,
 analyzing the defects to detect extended objects, and
 analyzing the extended objects for repetition across the substrate.
 - 2. The method of claim 1, wherein the step of inspecting the substrate comprises an optical inspection.
 - 3. The method of claim 1, wherein the substrate is a monolithic semiconducting substrate having integrated circuitry thereon.
 - 4. The method of claim 1, wherein the substrate is a reticle.
 - 5. The method of claim 1, wherein the substrate is a mask.
 - 6. The method of claim 1, wherein the extended objects include at least one of clusters and signatures.
 - 7. The method of claim 1, wherein the step of analyzing the defects to detect extended objects includes specifying a bounding box size.
 - 8. The method of claim 1, wherein the step of analyzing the extended objects for repetition includes specifying a bounding box size.
 - 9. The method of claim 1, wherein the step of analyzing the extended objects for repetition includes specifying a bounding box orientation.
 - 10. The method of claim 1, wherein the step of analyzing the extended objects for repetition includes specifying a bounding box overlap.
 - 11. A method for analyzing defects on a semiconductor substrate, the method including the steps of: optically inspecting the substrate to detect the defects,

- identifying the defects by location,
 analyzing the defects to detect extended objects, and
- analyzing the extended objects for repetition.

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- 12. The method of claim 11, wherein the extended objects include at least one of clusters and signatures.
- 13. The method of claim 11, wherein the step of analyzing the defects to detect extended objects includes specifying a bounding box size.
- 14. The method of claim 11, wherein the step of analyzing the extended objects for repetition includes specifying a bounding box size.
- 15. The method of claim 11, wherein the step of analyzing the extended objects for repetition includes specifying a bounding box orientation.
- 16. The method of claim 11, wherein the step of analyzing the extended objects for repetition includes specifying a bounding box overlap.
- 17. An apparatus for analyzing defects on a substrate, the apparatus comprising:
 a sensor for inspecting the substrate,
 a stage for providing relative movement between the sensor and the substrate, and
 a controller for:
 - correlating defect information from the sensor and position information from the stage,
 - analyzing the correlated defect information and position information to detect extended objects, and
 - analyzing the extended objects for repetition across the substrate.
- 18. The apparatus of claim 17 further comprising an input for receiving at least one of a bounding box size, a bounding box orientation, and a bounding box overlap as adjustable parameters for use in detecting and analyzing the extended objects for repetition.

- 19. The apparatus of claim 17 wherein the substrate is at least one of a semiconductor substrate, a reticle, and a mask.
- 20. The apparatus of claim 17 wherein the sensor is an optical sensor.